APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention

[LOW-TEMPERATURE POLYSILICON THIN FILM TRANSISTOR AND FABRICATION METHOD THEREOF]

Application Type: regular, utility 13137-US-PA Attorney Docket Number:

Correspondence address:

Customer Number: 31561

Priority Data:

Doc.No: 93109432; Country -TW; Date: 2004-04-06 us-priority-claimed

Inventor Information:

Inventor 1:

Applicant Authority Type: Inventor TW Citizenship: Name prefix: Mr.

Given Name: Cheng Chang

Family Name: Kuo

Residence:

City of Residence: Taoyuan **Country of Residence:** TW

Address-1 of Mailing Address: No. 189, Huaya 2nd Rd., Gueishan Shiang,

Address-2 of Mailing Address:

City of Mailing Address: Taoyuan

State of Mailing Address:

Postal Code of Mailing Address:

TW Country of Mailing Address:

Phone: Fax:

E-mail:

Attorney Information:

practitioner(s) at Customer Number:

31561



as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.